## Structure of monolayer FeSe on SrTiO<sub>3</sub> deciphered

## Picoscale structural insight into superconductivity of monolayer $FeSe/SrTiO_3$

Authors: Rui Peng, Ke Zou, M. G. Han, Stephen D. Albright, Hawoong Hong, Claudia Lau, H. C. Xu, Yimei Zhu, F. J. Walker, and C. H. Ahn Sci. Adv. **6**, eaay4517 (2020)

Recommended with a Commentary by Atsushi Fujimori, National Tsinghua University

In 2012, an order of magnitude enhancement of  $T_c$  (up to ~ 40-80 K) in monolayer FeSe grown on a SrTiO<sub>3</sub> (STO) substrate [1] invoked tremendous interest. Possible mechanisms of the  $T_c$  enhancement such as coupling to high-energy phonons of STO have been proposed. In particular, forward scattering of electrons by the STO phonons are considered to boost the  $T_c$ [2,3]. Another remarkable characteristic of the FeSe/STO is heavy electron doping. The hole Fermi surfaces at the Brillouin-zone (BZ) center disappear and the electron pockets at the BZ corner expand, invalidating the widely accepted nesting mechanism of superconductivity for Fe pnictides. (Note that bulk FeSe has small hole pockets at the BZ center and small electron pockets centered at the BZ corner, and shows a low  $T_c$  of ~8 K.) The large electron pocket at the BZ corner and the relatively high  $T_c$  of 30-50 K have also been reported for other FeSe-based superconductors such as  $K_x Fe_{2-y}S_2$ , alkali-deposited multilayer FeSe, and  $Li_{1-x}Fe_xFeSeOH$  (see a commentary in Ref. [4]).

The discovery and most of subsequent studies on monolayer FeSe/STO have been made using surface-sensitive techniques such as STM and ARPES since the system is not accessible for many bulk experimental techniques. Lateral spatial periodicities such as a  $2 \times 1$ superstructure [5] and stripe-type charge modulation (a smectic state with the wave length of ~1.9 nm) near defects [6] have been observed by STM. In order to supplement the limited experimental information, structural optimization utilizing density-functional theory (DFT) predicted a large number of oxygen vacancies, leading to the  $2 \times 1$  superstructure observed by STM, and strong bonding of the bottom Se atoms of the FeSe layer to the Ti-hollow sites of STO [5]. However, the stacking of atomic layers, their chemical compositions, and the position of each atom in each layer had remained unknown until recently.

In 2016, a transmission-electron-microscope (TEM) study revealed that the topmost layer of the STO substrate is indeed TiO<sub>2</sub> <u>double</u> layers rather than the TiO<sub>2</sub> layer of simple bulk termination [7]. The top layer of the double TiO<sub>2</sub> layers may, however, be highly oxygendeficient, considering the DFT study mentioned above [5]. In the recommended article, Peng et al. determined the atomic positions and chemical compositions of several atomic layers at



Figure 1: Structures of the monolayer FeSe/SrTiO<sub>3</sub>(001) as revealed by Peng <u>et al.</u> in the recommended article. a and b denote the orthorhombic axes of the FeSe layer. b is slightly shorter than a in the nematic and (bulk) stripe-type antiferromagnetic (AFM) phases. In the topmost TiO<sub>x</sub> layer of the STO substrate, the number of oxygen atoms (not shown) is small and Ti atoms are heavily displaced from the ideal positions.

the FeSe/STO interface by x-ray diffraction (XRD) on <u>in-situ</u> prepared samples. XRD from a surface or interface yields Bragg rods instead of Bragg spots, so-called crystal-truncation rods (CTR), whose intensity profile can be used to determine the atomic positions perpendicular to the interface/surface as well in the lateral directions and their site occupancies. (The CTR analysis has been successfully applied, e.g., to the celebrated LaAlO<sub>3</sub>/SrTiO<sub>3</sub> interface [8].) Salient features of the CTR analysis were:

- 1. The topmost layer of the  $\text{TiO}_2$  double layers is highly oxygen deficient:  $\text{TiO}_x$ . This provides the FeSe layer with the high concentration of electrons.
- 2. The registry of the FeSe lattice relative to the STO substrate is such that the bottom Se atoms are located above hollow sites between two Ti atoms of the  $\text{TiO}_x$  layer, as shown in Fig. 1.
- 3. The monolayer FeSe is thus coherently strained by the substrate. The strain is tensile and reduces the Se-Fe-Se bond angle, making it closer to the optimal value of  $109.5^{\circ}$  (for the ideal FeSe<sub>4</sub> tetrahedron).

4. The distance between the bottom Se and the  $\text{TiO}_x$  layer is as small as 0.292 nm (Fig. 1). This results in strong bonding between the FeSe layer and the substrate and hence strong coupling of electrons in FeSe to STO phonons.

Among the above findings, 2-4 likely favor the enhancement of the  $T_c$ . As for 1, the dramatic changes in the electronic structure caused by the heavy electron doping lead to the large shift of the spin-fluctuation spectrum towards higher energies as probed by resonant inelastic xray scattering (RIXS) [9], which will enhance the  $T_c$  within the spin-fluctuation-mediated pairing scenario.

All the above effects of 1-4 should be the strongest for monolayer FeSe and would fade away as the number of FeSe layers increases. If the doped electron concentration decreases away from the interface, the bulk-like nematic order will revive and compete with the superconductivity, thereby reducing the  $T_c$ . This was proved by a recent STM study, which showed that a stripy charge-ordered phase (a smectic phase emerging from the nematic state) with a long wavelength of ~1.9 nm appeared and the superconductivity disappears for FeSe-film thicknesses above two monolayer [10]. Also, K deposition on the smectic FeSe suppressed the charge order and superconductivity of  $T_c \sim 50$  K recovered.

Considering the strong coupling between magnetism and crystal structures known for bulk Fe compounds and related materials [11], it is likely that the characteristic hardening of spin fluctuations observed by RIXS [9], which can lead to the  $T_c$  enhancement, is caused not only by the increased electron doping as discussed above but also by the characteristic structure of the monolayer FeSe/STO.

## References

- Q.-Y. Wang, Z. Li, W.-H. Zhang, Z.-C. Zhang, J.-S. Zhang, W. Li, H. Ding, Y.-B. Ou, P. Deng, K. Chang, J. Wen, C.-L. Song, K. He, J.-F. Jia, S.-H. Ji, Y.-Y. Wang, L.-L. Wang, X. Chen, X.-C. Ma, and Q.-K. Xue, *Interface-induced high-temperature superconductivity in single unit-cell FeSe films on SrTiO*<sub>3</sub>, Chin. Phys. Lett. **29**, 037402 (2012).
- [2] J. J. Lee, F. T. Schmitt, R. G. Moore, S. Johnston, Y.-T. Cui, W. Li, M. Yi, Z. K. Liu, M. Hashimoto, Y. Zhang, D. H. Lu, T. P. Devereaux, D.-H. Lee, and Z.-X. Shen, *Interfacial mode coupling as the origin of the enhancement of T<sub>c</sub> in FeSe films on SrTiO<sub>3</sub>*, Nature 515, 245 (2014).
- [3] D.-H. Lee, What makes the  $T_c$  of  $FeSe/SrTiO_3$  so high? Chin. Phys. B 24, 117405 (2015).
- [4] A. Fujimori, From monolayer back to bulk FeSe-based high-temperature superconductors, Journal Club for Condensed Matter Physics, February 2016. DOI: 10.36471/JCCM\_February\_2016\_01.
- [5] J. Bang, Z. Li, Y. Y. Sun, A. Samanta, Y. Y. Zhang, W. Zhang, L. Wang, X. Chen, X. Ma, Q.-K. Xue, and S. B. Zhang, Atomic and electronic structures of single-layer FeSe on SrTiO<sub>3</sub>(001): The role of oxygen deficiency, Phys. Rev. B 87, 220503(R) (2013).

- [6] W. Li, Y. Zhang, P. Deng, Z. Xu, S.-K. Mo, M. Yi, H. Ding, M. Hashimoto, R. G. Moore, D.-H. Lu, X. Chen, Z.-X. Shen, and Q.-K. Xue, *Stripes developed at the strong limit of nematicity in FeSe film*, Nat. Phys. 13, 957 (2017).
- [7] K. Zou, S. Mandal, S. D. Albright, R. Peng, Y. Pu, D. Kumah, C. Lau, G. H. Simon, O. E. Dagdeviren, X. He, I. Božović, U. D. Schwarz, E. I. Altman, D. Feng, F. J. Walker, S. Ismail-Beigi, and C. H. Ahn, *Role of double TiO<sub>2</sub> layers at the interface of FeSe/SrTiO<sub>3</sub> superconductors*, Phys. Rev. B **93**, 180506(R) (2016).
- [8] P. R. Willmott, S. A. Pauli, R. Herger, C. M. Schleputz, D. Martoccia, B. D. Patterson, B. Delley, R. Clarke, D. Kumah, C. Cionca, and Y. Yacoby, *Structural basis for the conducting interface between LaAlO<sub>3</sub> and SrTiO<sub>3</sub>*, Phys. Rev. Lett. **99**, 155502 (2007).
- [9] J. Pelliciari, S. Karakuzu, Q. Song, R. Arpaia, A. Nag, M. Rossi, J. Li, T. Yu, X. Chen, R. Peng, M. Garcia-Fernandez, A. C. Walters, Q. Wang, J. Zhao, G. Ghiringhelli, D. Feng, T. A. Maier, K.-J. Zhou, S. Johnston, and R. Comin, *Evolution of spin excitations from bulk to monolayer FeSe*, Nat. Commun. **12**, 3122 (2021).
- [10] Y. Yuan, X. Fan, X. Wang, K. He, Y. Zhang, Q.-K. Xue, and W. Li, Incommensurate smectic phase in close proximity to the high-T<sub>c</sub> superconductor FeSe/SrTiO<sub>3</sub>, Nat. Commun. **12**, 2196 (2021).
- [11] T. Egami, B. V. Fine, D. Parshall, A. Subedi, and D. J. Singh, Spin-lattice coupling and superconductivity in Fe pnictides, Advances in Condensed Matter Physics 2010, 164916 (2010).